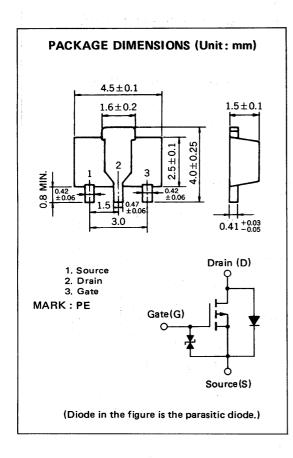


MOS FIELD EFFECT TRANSISTOR 2SJ207

P-CHANNEL MOS FET FOR SWITCHING



The 2SJ207, P-channel vertical type MOS FET, is a switching device which can be driven by 2.5 V power supply.

As the MOS FET is driven by low voltage and does not require consideration of driving current, it is suitable for appliances including VCR cameras and headphone stereo which need power saving.

FEATURES

- Directly driven by ICs having a 3 V power supply.
- Not necessary to consider driving current because of its high input impedance.
- Possible to reduce the number of parts by omitting the bias resistor.
- Has low on-state resistance

$$R_{DS(on)} = 4.0 \Omega MAX$$
. @ $V_{GS} = -2.5 V$, $I_D = -30 mA$
 $R_{DS(on)} = 1.5 \Omega MAX$. @ $V_{GS} = -4.0 V$, $I_D = -500 mA$

QUALITY GRADE

Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C)

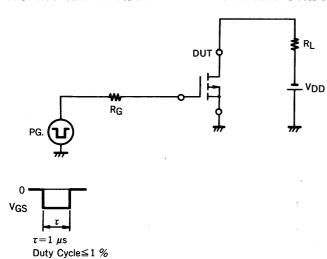
| PARAMETER | SYMBOL | RATINGS | UNIT | TEST CONDITIONS |
|-------------------------|------------------------|-------------|------|---|
| Drain to Source Voltage | V _{DSS} | -16 | · V | V _{GS} = 0 |
| Gate to Source Voltage | V _{GSS} | ∓16 | V | V _{DS} = 0 |
| Drain Current | ID(DC) | ∓1.0 | A | |
| Drain Current | I _D (pulse) | ∓2.0 | Α | PW ≦ 10 ms, Duty Cycle ≦ 50 % |
| Total Power Dissipation | PT | 2.0 | W | When using ceramic board of 16 cm ² x 0.7 mm |
| Channel Temperature | T _{ch} | 150 | °c | |
| Operating Temperature | Topt | -55 to +80 | °C | |
| Storage Temperature | T _{stg} | -55 to +150 | °C | |

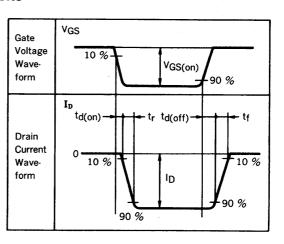


ELECTRICAL CHARACTERISTICS (T_a = 25 °C)

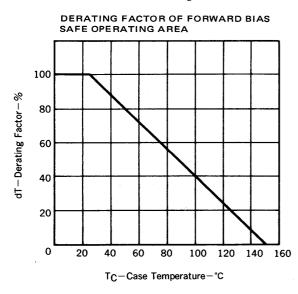
| PARAMETER | SYMBOL | MIN. | TYP. | MAX. | UNIT | TEST CONDITIONS | |
|-------------------------------------|----------------------|------|------|------|------|---|--|
| Drain Cut-off Current | IDSS | | | -1.0 | μΑ | V _{DS} = -16 V, V _{GS} = 0 | |
| Gate Leakage Current | IGSS | | | ∓5.0 | μΑ | V _{GS} = ∓16 V, V _{DS} = 0 | |
| Gate Cut-off Voltage | V _{GS(off)} | -1.4 | -1.9 | -2.4 | ·V | $V_{DS} = -5 \text{ V, I}_{D} = -1 \text{ mA}$ | |
| Forward Transfer Admittance | lyfsl | 0.4 | 0.7 | | S | $V_{DS} = -3 \text{ V, } I_{D} = -500 \text{ mA}$ | |
| Drain to Source On-State Resistance | R _{DS(on)1} | | 2.6 | 4.0 | Ω | V _{GS} = -2.5 V, I _D = -30 mA | |
| Drain to Source On-State Resistance | R _{DS(on)2} | | 0.9 | 1.5 | Ω | V _{GS} = -4.0 V, I _D = -500 mA | |
| Input Capacitance | Ciss | | 180 | | pF | | |
| Output Capacitance | Coss | | 160 | | pF | $V_{DS} = -3.0 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$ | |
| Feedback Capacitance | C _{rss} | | 50 | | pF | 1 | |
| Turn-On Delay Time | ^t d(on) | | 180 | | ns | | |
| Rise Time | t _r | | 500 | | ns | $V_{GS(on)} = -3 \text{ V, R}_{G} = 10 \Omega, V_{DD} = -3 \text{ V,}$ $I_{D} = -100 \text{ mA, R}_{L} = 30 \Omega$ | |
| Turn-Off Delay Time | ^t d(off) | | 130 | | ns | | |
| Fall Time | tf | | 240 | | ns | | |

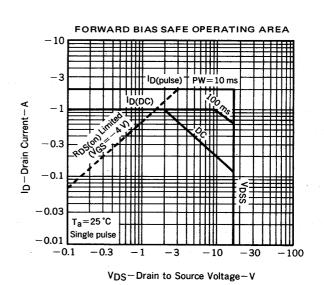
SWITCHING TIME MEASUREMENT CIRCUIT AND CONDITIONS

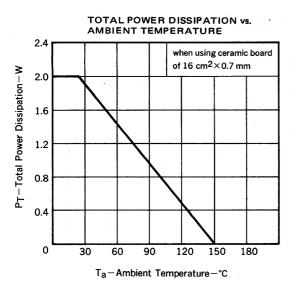


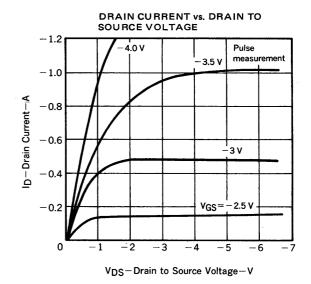


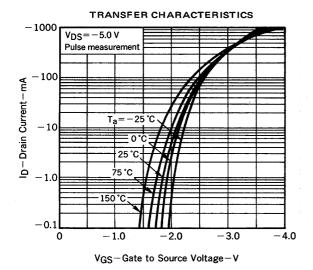
TYPICAL CHARACTERISTICS (T_a = 25 °C)

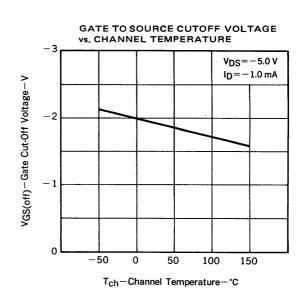


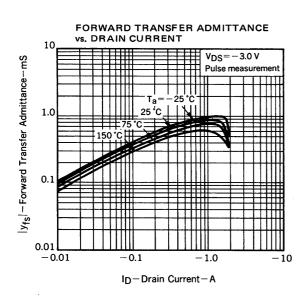


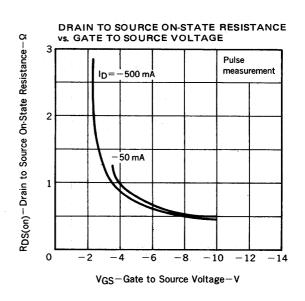


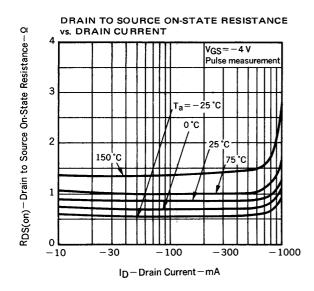


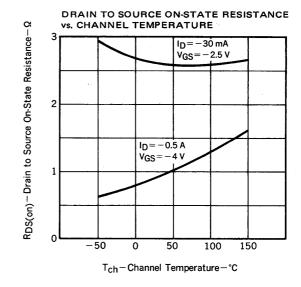


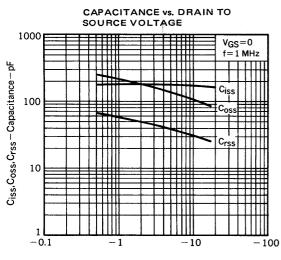


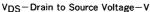


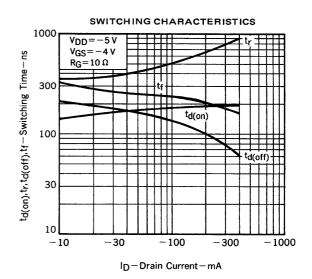


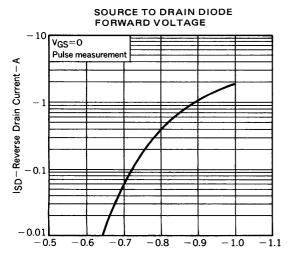












VSD-Source to Drain Voltage-V



RECOMMENDED SOLDERING CONDITIONS

Mounting of this product by soldering should be done under the following conditions. Please consult our representatives about soldering methods and conditions other than these.

SURFACE MOUNT TYPE

For details of the recommended soldering conditions, see the information document.

"Device Mounting Manual for Surface Mounting (IEI-1207)."

| Soldering Method | Soldering Conditions | Symbol for Recommended Conditions | |
|-----------------------|--|--------------------------------------|--|
| Infrared Reflow | Package peak temp.: 230 °C Soldering time: within 30 sec (above 210 °C) Soldering time: 1, Days limitation: none* | IR30-00 | |
| Vapor Phase Soldering | Package peak temp.: 215 °C Soldering time: within 40 sec (above 200 °C) Soldering times: 1, Days limitation: none* | VP15-00 | |
| Wave Soldering | Soldering bath temp.: below 260 °C Soldering time: within 10 sec Soldering times: 1, Days limitation: none* | WS60-00 | |

^{*} Stored days under storage conditions as 25 °C and below 65 % R.H. after the dry-pack has been opened.

Note 1: Combination of soldering methods should be avoided.

REFERENCE

| Document Name | Document No. | |
|--|--------------|--|
| NEC semiconductor device reliability/quality control system. | TEI-1202 | |
| Quality grade on NEC semiconductor devices. | IEI-1209 | |
| Semiconductor device mounting technology manual. | IEI-1207 | |
| Semiconductor device package manual. | IEI-1213 | |
| Guide to quality assurance for semiconductor devices. | MEI-1202 | |
| Semiconductor selection guide. | MF-1134 | |

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Application examples recommended by NEC Corporation

Standard: Computer, Office equipment, Communication equipment, Test and Measurement equipment, Machine tools, Industrial robots, Audio and Visual equipment, Other consumer products, etc.

Special: Automotive and Transportation equipment, Traffic control systems, Antidisaster systems, Anticrime systems, etc.

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